This GIDEP PCN is to announce specifications change with the datasheet parameters for the following International Rectifier Part No. Note that this change is related to part specification only, and not due to a die physical change.

**IRHNA67160 (2N7579U2)**
100V, N-Channel, TID Hardened MOSFET in a SMD-2 package

**RADIATION CHARACTERISTICS CHANGE:**
Table 1 Electrical Characteristics @ Tj = 25°C, Post Total Dose Irradiation

| Vs0 [Diode Forward Voltage] | change maximum limit for up to 300kRads(Si) from 1.3V to 1.2V |

Reference Datasheet PD-94299